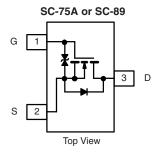




# N-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (mA)		
	0.70 at V <sub>GS</sub> = 4.5 V	600		
20	0.85 at V <sub>GS</sub> = 2.5 V	500		
	1.25 at V <sub>GS</sub> = 1.8 V	350		



ORDERING INFORMATION					
Part Number	Package	Marking Code			
Si1012R-T1-GE3 (Lead (Pb)-free and Halogen-free)	SC-75A (SOT-416)	С			
Si1012X-T1-GE3 (Lead (Pb)-free and Halogen-free)	SC-89 (SOT-490)	А			

#### **FEATURES**





Gate-Source ESD Protected: 2000 V

High-Side Switching

Low On-Resistance: 0.7 Ω
 Low Threshold: 0.8 V (typ.)
 Fast Switching Speed: 10 ns

• Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- · Battery Operated Systems
- Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

#### **BENEFITS**

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- · Low Battery Voltage Operation

<b>ABSOLUTE MAXIMUM RATINGS</b> (	$T_A = 25 ^{\circ}C$ , unless	otherwise no	ted)			
Parameter	Symbol	5 s	Steady State	Unit		
Drain-Source Voltage		V <sub>DS</sub>	20		V	
Gate-Source Voltage		V <sub>GS</sub>				
Continuous Dunin Comment /T 150 °C\b	T <sub>A</sub> = 25 °C	1-	600	500		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>b</sup>	T <sub>A</sub> = 85 °C	- I <sub>D</sub>	400	350		
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	1000		mA	
Continuous Source Current (Diode Conduction) <sup>b</sup>		I <sub>S</sub>	275	250		
W :	T <sub>A</sub> = 25 °C		175	150	mW	
Maximum Power Dissipation <sup>b</sup> for SC-75	T <sub>A</sub> = 85 °C	] 📙	90	80		
	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	275	250		
Maximum Power Dissipation <sup>b</sup> for SC-89	T <sub>A</sub> = 85 °C		160	140		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Gate-Source ESD Rating (HBM, Method 3015)	ESD		V			

#### Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface mounted on FR4 board.

Pb-free

ROHS COMPLIANT HALOGEN FREE

## Si1012R/X

# Vishay Siliconix



<b>SPECIFICATIONS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$ 0.45			0.9	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 0.5	± 1.0	μΑ		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V		0.3	100	nA		
		$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			5	μΑ		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 4.5 V	700			mA		
		$V_{GS} = 4.5 \text{ V}, I_D = 600 \text{ mA}$		0.41	0.70	Ω		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 500 \text{ mA}$		0.53	0.85			
		$V_{GS} = 1.8 \text{ V}, I_D = 350 \text{ mA}$		0.70	1.25			
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 400 mA		1.0		S		
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 150 mA, V <sub>GS</sub> = 0 V		0.8	1.2	V		
Dynamic <sup>b</sup>								
Total Gate Charge	$Q_g$			750				
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 250 \text{ mA}$		75		рС		
Gate-Drain Charge	$Q_{gd}$			225				
Turn-On Delay Time	t <sub>d(on)</sub>			5				
Rise Time	t <sub>r</sub>	$t_r$ $V_{DD} = 10 \text{ V, } R_L = 47 \Omega$		5		ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 200 \text{ mA}, V_{GEN} = 4.5 \text{ V}, R_g = 10 \Omega$	!	25				
Fall Time	t <sub>f</sub>			11				

#### Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

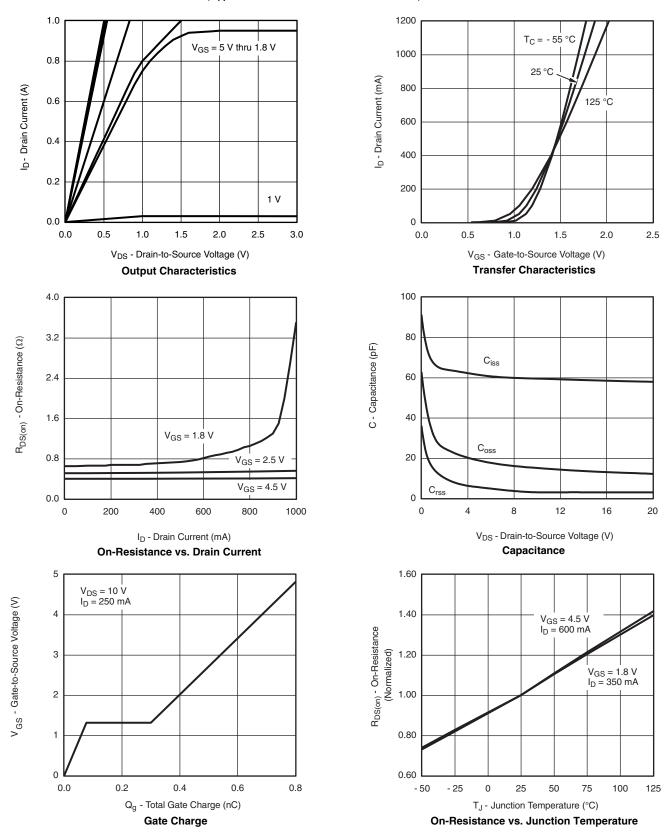
a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.





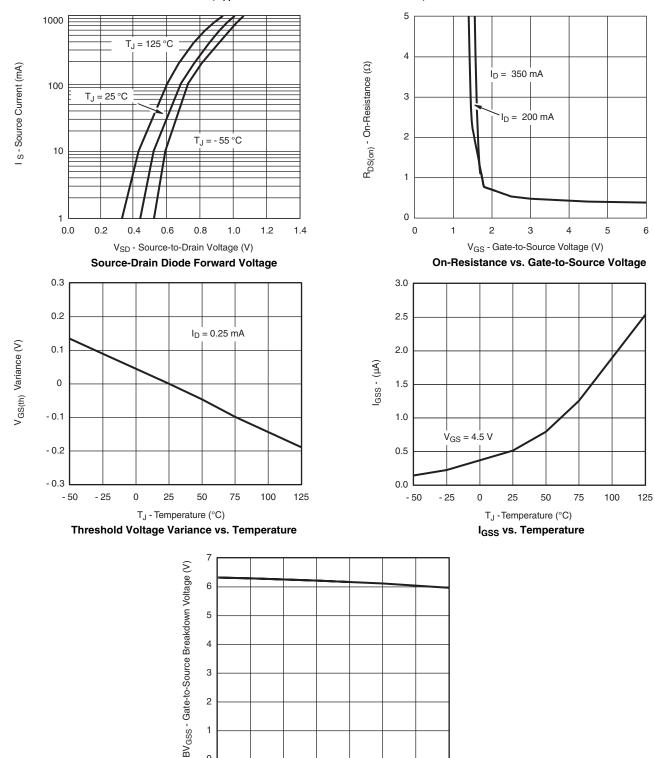
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



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## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



- 25

25

 $T_J$  - Temperature (°C) BV<sub>GSS</sub> vs. Temperature

50

75

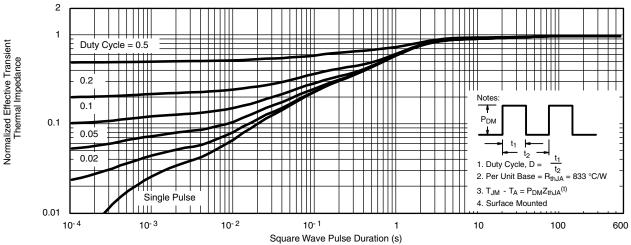
- 50

125

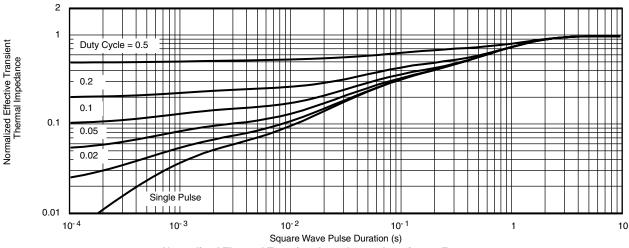
100



### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A)



Normalized Thermal Transient Impedance, Junction-to-Foot

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